Intro. to Electro-physics The band theory and semiconductors (I)

Jaesang Lee Dept. of Electrical and Computer Engineering Seoul National University (email: jsanglee@snu.ac.kr)



Free vs. nearly-free electron models (1/2)

Free electron model

- **can** explain limited aspects of heat capacity, thermal conductivity, electrical conductivity and etc.
- **cannot** predict the positive Hall coefficient and many detailed transport properties
- cannot distinguish between metals, semiconductors and insulators
- **Nearly-free electron model** \bullet

 $\frac{\hbar^2}{2m} \frac{d^2 \psi(x)}{dx} + V(x) \psi(x) = E \psi(x), \text{ where}$

- Solution $\psi(x)$: Bloch's state
- -----
 - Metal: one more more bands are partly filled ►
 - Insulator: bands are either completely empty or filled ►
 - Semiconductor: one or two bands are slightly filled or slightly empty ►

- Electrons move nearly freely, while being subject to a weak, periodic potential due to the periodic lattice

$$V(x + na) = V(x)$$

The most important property of solids, "allowed bands" and "forbidden gaps", emerges as a result!





Free vs. nearly-free electron models (2/2)

Free electron model

- Dispersion relation (ε vs. k)

$$\varepsilon_{k} = \frac{\hbar^{2}}{2m} \left(k_{x}^{2} + k_{y}^{2} + k_{z}^{2} \right), \text{ where } \left(k_{x}, k_{y}, k_{z} \right) = 0, :$$

- Wave function for a free electron $\psi_k = \exp\left(i\boldsymbol{k}\cdot\boldsymbol{r}\right)$

: Traveling wave that carries a momentum $p = \hbar k$

Nearly-free electron model

- The electrons in crystals perturbed "only weakly" by the periodic potential of the ion cores
- **Bragg reflection** at Brillouin zone boundary occurs -
 - a characteristic feature of wave propagation in crystals
 - the cause of **energy gaps**





Free electron model



Nearly-free electron model







Origin of a band gap (1/2)

- 1D model •
 - The Bragg condition in 1D

$$2\mathbf{k} \cdot \mathbf{G} = G^2 \longrightarrow k = \pm \frac{1}{2}G = \pm \frac{n\pi}{a}$$
, where $G = \frac{1}{2}G = \pm \frac{n\pi}{a}$

- The first Brillouin zone in *k*-space = $|-\pi/a, \pi/a|$
- At zone boundaries $(k = \pm \pi/a)$
 - A wave traveling to the right is Bragg-reflected to travel to the left, and vice versa
 - Two waves traveling to the left & right :

$$\exp\left(\pm i\frac{\pi x}{a}\right) = \cos\left(\frac{\pi x}{a}\right) \pm i\sin\left(\frac{\pi x}{a}\right)$$

Two standing waves are resulted :

$$\begin{cases} \psi_{+} = \exp(i\pi x/a) + \exp(-i\pi x/a) = 2\cos(i\pi x/a) \\ \psi_{-} = \exp(i\pi x/a) - \exp(-i\pi x/a) = 2i\sin(i\pi x/a) \end{cases}$$



 $(\pi x/a)$ $(\pi x/a)$



Origin of a band gap (2/2)

- Probability density of a wave-like particle $\rho = \left|\psi\right|^2 = \psi^*\psi$
 - Probability density for a traveling wave $\rho_0 = \exp\left(-ikx\right) \exp\left(ikx\right) = 1$
 - Probability density for waves in crystals -

$$\begin{cases} \rho_{+} = \left| \psi_{+} \right|^{2} \propto \cos^{2} (\pi x/a) \\ \rho_{-} = \left| \psi_{-} \right|^{2} \propto \sin^{2} (\pi x/a) \end{cases}$$

- ρ_+ piles up electrons on the positive ions, where the potential energy is lowest
- ρ_{-} concentrates electrons away from the ion cores

The average of the potential energy & energy gap

 $U_{\rho_+} < U_{\rho_0} < U_{\rho_-} \text{ and } U_{\rho_-} - U_{\rho_+} \triangleq E_g$



Bloch theorem

- Bloch theorem
 - The solutions of the Schrödinger equation for a periodic potential is given in a form :

$$\psi_k(\mathbf{r}) = u_k(\mathbf{r}) \exp(i\mathbf{k}\cdot\mathbf{r})$$
, where $u_k(\mathbf{r}+\mathbf{T})$

- $u_k(\mathbf{r})$: a periodic function
- $T = v_1 a_1 + v_1 a_2 + v_1 a_3$: Translation vector of a lattice
- $\exp(i\mathbf{k} \cdot \mathbf{r})$: propagation (with an oscillation strength and direction)
- Probability of finding an electron at *r*

$$P_{k}(\mathbf{r}) = \left| \psi_{k}(\mathbf{r}) \right|^{2} = \left| u_{k}(\mathbf{r}) \exp\left(i\mathbf{k} \cdot \mathbf{r}\right) \right|^{2} = \left| u_{k}(\mathbf{r}) \right|^{2} \left(\because \left| \exp\left(i\mathbf{k} \cdot \mathbf{r}\right) \right| = 1 \right)$$

$$\therefore P_k(r+T) = P_k(r)$$

Probability of finding an electron at r in the unit cell = that in "every" cell of the whole crystal

Such electronic state = Bloch's state = Delocalized state

 $') = u_k(\mathbf{r})$

Felix Bloch (Switzerland) 1905-1983



1D model for a band structure (1/3)

- Simple 1D Dirac-comb model
 - Schrödinger's equation with a periodic potential V(x)

 $-\frac{\hbar^2}{2m}\frac{d^2\psi}{dx^2} + V\psi = E\psi, \text{ where } V(x+a) = V(x)$

- 1D Dirac-comb potential

$$V(x) = \alpha \sum_{j=0}^{N-1} \delta \left(x - ja \right)$$

- Periodic boundary condition (ring-shaped) $\psi(x + Na) = \psi(x), \ (N > 10^{23} \text{cm}^{-3} : \text{number of atoms})$
- Bloch's theorem in 1D

 $\psi(x + a) = e^{iqa}\psi(x)$ (for some constant *q*)





1D model for a band structure (2/3)

- Simple 1D Dirac-comb model (contd.)
 - By combining Bloch's theorem & periodic boundary condition,

•
$$\left[\psi(x + Na) = e^{iqNa}\psi(x)\right] = \psi(x)$$

•
$$e^{iqNa} = 1 \longrightarrow qNa = 2\pi n$$

 $\therefore q = \frac{2\pi n}{Na}, \quad (n = 0, \pm 1, \pm 2, \cdots)$

- (revisited) Schrödinger's equation
 - Wavefunction within the 1st unit cell (0 < x < a) where V(x) = 0

$$-\frac{\hbar^2}{2m}\frac{d^2\psi}{dx^2} + V\psi = E\psi \longrightarrow -\frac{\hbar^2}{2m}\frac{d^2\psi}{dx^2} = E$$

$$\frac{d^2\psi}{dx^2} = -k^2\psi, \quad \text{where } k = \frac{\sqrt{2mE}}{\hbar}$$

$$\psi(x) = A\sin(kx) + B\cos(kx), \quad (0 < x < a)$$

 $\psi(x + Na) = \psi(x)$: B.C. $\psi(x + a) = e^{iqa}\psi(x)$: Bloch's theorem



ZΨ





1D model for a band structure (3/3)

- Schrödinger's equation (revisited)
 - wavefunction for the N^{th} cell immediately to the left of the origin:

 $\psi(x - a) = e^{-iqa}\psi(x), \quad (0 < x < a) \quad (::Bloch's theorem)$ Let $x' \triangleq x - a$. Then, $\Psi(x') = e^{-iqa} \left[A \sin q (x' + a) + B \cos k (x' + a) \right]$

- Boundary condition ullet
 - $\psi(x)$ must be continuous at x = 0:

$$B = e^{-iqa} \left[A \sin(ka) + B \cos(ka) \right] \dots \textcircled{0}$$

$$d\psi(x)/dx \text{ suffers a discontinuity due to the delta function :}$$

$$kA - e^{-iqa}k \left[A \cos(ka) - B \sin(ka) \right] = \frac{2m\alpha}{\hbar^2} B \dots \textcircled{0}$$

$$d\psi(x)/dx = \frac{1}{2\pi} \left[A \cos(ka) - B \sin(ka) \right] = \frac{2m\alpha}{\hbar^2} B \dots \textcircled{0}$$

$$d\psi(x)/dx = \frac{1}{2\pi} \left[A \cos(ka) - B \sin(ka) \right] = \frac{2m\alpha}{\hbar^2} B \dots \textcircled{0}$$

$$d\psi(x)/dx = \frac{1}{2\pi} \left[A \cos(ka) - B \sin(ka) \right] = \frac{2m\alpha}{\hbar^2} B \dots \textcircled{0}$$

$$d\psi(x)/dx = \frac{1}{2\pi} \left[A \cos(ka) - B \sin(ka) \right] = \frac{2m\alpha}{\hbar^2} B \dots \textcircled{0}$$

$$d\psi(x)/dx = \frac{1}{2\pi} \left[A \cos(ka) - B \sin(ka) \right] = \frac{2m\alpha}{\hbar^2} B \dots \textcircled{0}$$

],
$$(-a < x' < 0)$$

Wavefunction in the 1st unit cell $\psi(x) = A\sin(kx) + B\cos(kx)$ 2a



Band structure (1/2)

- Band structure ullet
 - Solution to Schrödinger's equation for a periodic potential :

$$\cos(qa) = \cos(ka) + \frac{m\alpha}{\hbar^2 k} \sin(ka)$$
, where $q = \frac{2\pi}{N}$

- For simplicity, let $ka \triangleq z$ and $\frac{m\alpha a}{\hbar^2} \triangleq \beta$

$$\left[\cos\left(qa\right) = \cos\left(\frac{2\pi n}{N}\right)\right] = \left[\cos z + \beta \frac{\sin z}{z} \triangleq f(z)\right]$$

 $\left|\cos\left(\frac{2\pi n}{N}\right)\right|$ ≤ 1 : The region where solutions exist (allowed band) ►

$$\left| \cos \left(\frac{2\pi n}{N} \right) \right| > 1$$
: The region with no solutions (f



forbidden gap)



Band structure (2/2)

- Band structure ullet
 - Allowed band
 - Intercepts between N horizontal lines and $f(z) \rightarrow N$ solutions ►
 - In each band, there are closely spaced N electronic states N
 - Since $N \gg 10^{23}$ (cm³), a continuum of N electronic states = Band
 - Band structure = alternating bands and gaps
 - Band structure = a signature of a periodic potential
- Ground state of multi-electrons atomic crystal •
 - Each state can accommodate 2 electrons (: Exclusion principle)
 - d: the number of valence electrons per atom
 - d = 1: Half fill the first band
 - d = 2: Completely fill the first band
 - d = 3: Half fill the second band
 - ...and so on





